



**DESCRIPTION**

The AM10T65 is available in TO-252 Packages.

V <sub>CES</sub>	650V
IC	15A
V <sub>CE (sat).typ</sub>	1.4V
P <sub>D</sub> (T <sub>C</sub> =25°C)	35W

**APPLICATION**

- UPS
- Air Condition
- Motor Drives
- PFC

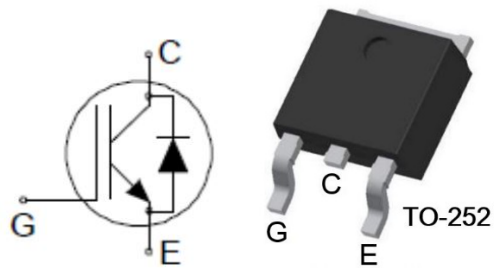
**ORDERING INFORMATION**

Package Type	Part Number	
TO-252 SPQ:2,500pcs /Reel	D	AM10T65R
		AM10T65VR
Note	V: Halogen free Package R: Tape & Reel	
AiT provides all RoHS products		

**FEATURE**

- Fast Switching
- Low V<sub>CE (sat)</sub>
- Positive temperature coefficient
- Very soft, fast recovery anti-parallel diode

**PIN DESCRIPTION**



Pin#	Symbol	Function
1	G	Gate
2	C	Collector
3	E	Emitter



## ABSOLUTE MAXIMUM RATINGS

T<sub>A</sub> = 25°C, unless otherwise specified.

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CES</sub>	650	V
Collector Current @ T <sub>C</sub> = 25 °C	I <sub>C</sub>	30	A
Collector Current @ T <sub>C</sub> = 100 °C		10	A
Pulsed Collector Current * @ T <sub>C</sub> = 25 °C	I <sub>CM</sub>	40	A
Diode Continuous Forward Current @ T <sub>C</sub> = 25 °C	I <sub>F</sub>	20	A
Diode Continuous Forward Current @ T <sub>C</sub> = 100 °C		10	A
Diode Maximum Forward Current @ T <sub>C</sub> = 25 °C	I <sub>FM</sub>	30	A
Gate-Emitter Voltage	V <sub>GES</sub>	±30	V
Power Dissipation @ T <sub>C</sub> = 25 °C	P <sub>D</sub>	83	W
Operating Junction Temperature Range	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to 150	°C
Maximum Temperature for Soldering	T <sub>L</sub>	260	°C
<b>THERMAL RESISTANCE</b>			
Junction-to-Case (IGBT)	R <sub>θJC</sub>	1.5	°C/W
Junction-to-Case (Diode)	R <sub>θJC</sub>	2.5	°C/W
Junction-to-Ambient	R <sub>θJA</sub>	62	°C/W

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

\*Pulse width limited by maximum junction temperature



**ELECTRICAL CHARACTERISTICS**

T<sub>A</sub> = 25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ.	Max.	Unit
<b>OFF CHARACTERISTICS</b>						
Collector-Emitter Breakdown Voltage	V <sub>CES</sub>	V <sub>GE</sub> = 0V, I <sub>C</sub> = 250μA	650	-	-	V
Collector-Emitter Leakage Current	I <sub>CES</sub>	V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V	-	-	4	μA
Gate-Emitter Leakage Current	I <sub>GES(F)</sub>	V <sub>GE</sub> = +30V	-	-	200	nA
Gate-Emitter Reverse Leakage	I <sub>GES(R)</sub>	V <sub>GE</sub> = -30V	-	-	-200	nA
<b>ON CHARACTERISTICS</b>						
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	V <sub>GE</sub> = 15V, I <sub>C</sub> = 10A	-	1.4	1.75	V
Gate Threshold Voltage	V <sub>GE(TH)</sub>	V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 1mA	4.5	5.2	5.9	V
Pulse width tp ≤ 300μs, δ ≤ 2%						
<b>Dynamic CHARACTERISTICS</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>GE</sub> = 0V	-	947	-	pF
Output Capacitance	C <sub>oss</sub>	V <sub>CE</sub> = 25V	-	32	-	
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz	-	9	-	
Total Gate Charge	Q <sub>g</sub>	I <sub>C</sub> = 10A V <sub>CE</sub> = 520V V <sub>GE</sub> = 15V	-	39	-	nC
<b>Switching CHARACTERISTICS</b>						
Turn-on Delay Time	td(on)	I <sub>C</sub> = 10A V <sub>CE</sub> = 400V V <sub>GE</sub> = 15V R <sub>G</sub> = 10Ω T = 25°C Inductive Load	-	20	-	ns
Rise Time	tr		-	8	-	
Turn-Off Delay Time	td(off)		-	73	-	
Fall Time	tf		-	65	-	
Turn-On Switching Loss	E <sub>on</sub>		-	0.15	-	mJ
Turn-Off Switching Loss	E <sub>off</sub>		-	0.24	-	
Total Switching Loss	E <sub>ts</sub>		-	0.39	-	
<b>Diode CHARACTERISTICS</b>						
Diode Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10A	-	1.8	2.1	V
Reverse Recovery Time	T <sub>rr</sub>	I <sub>F</sub> = 10A, di/dt = 200A/us,	-	127	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>		-	286	-	nC
Reverse Recovery Current	I <sub>rrm</sub>		-	4.4	-	A



## TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. Forward Bias Safe Operating Area

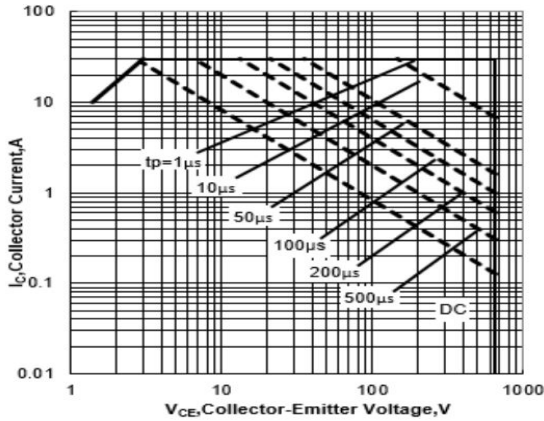


Fig 2. Power Dissipation vs Case Temperature

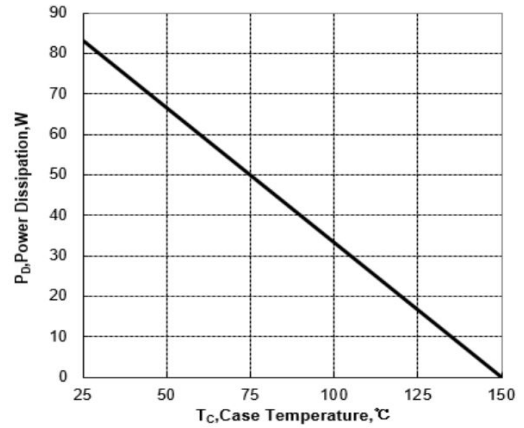


Fig 3. Collector Current vs Case Temperature

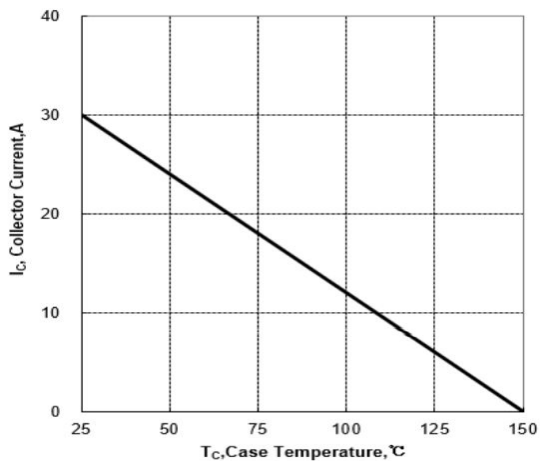


Fig 4. Typical Transfer Characteristics

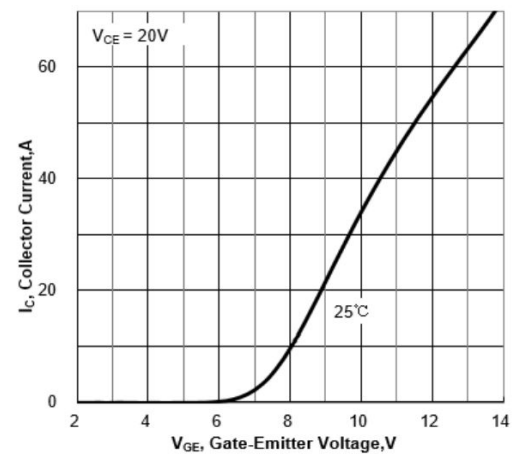


Fig 5. Typical Output Characteristics ( $T_A = 25^{\circ}C$ )

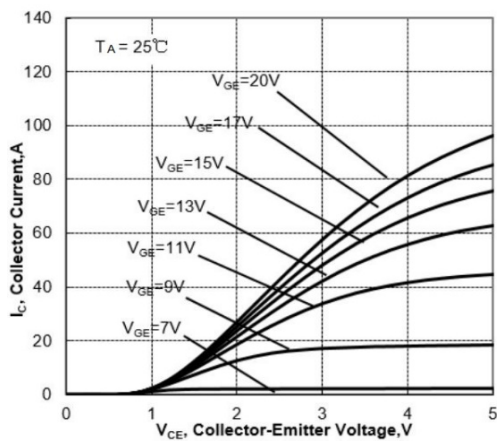


Fig 6. Typical Gate Charge

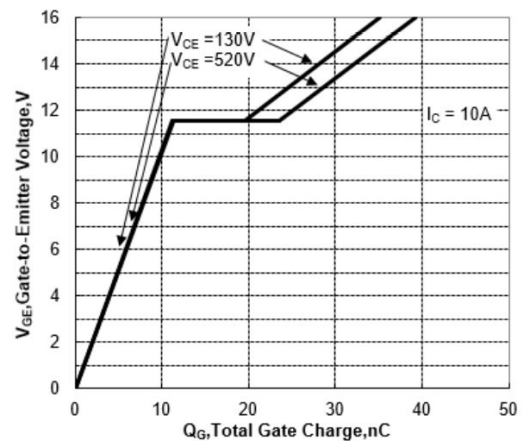




Fig 7. Typical Capacitance vs Collector-Emitter Voltage

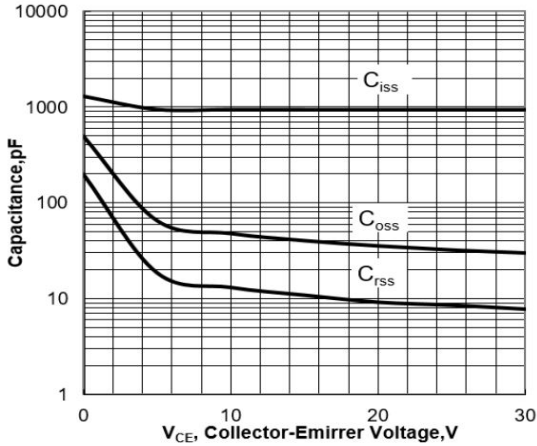


Fig 8. IGBT Transient Thermal Impedance vs Pulse Width

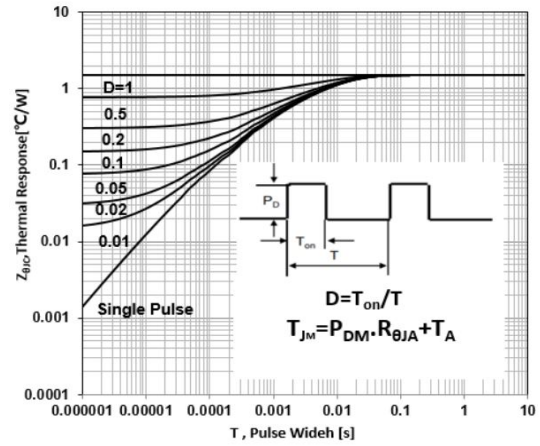


Fig 9. Diode Transient Thermal Impedance vs Pulse Width

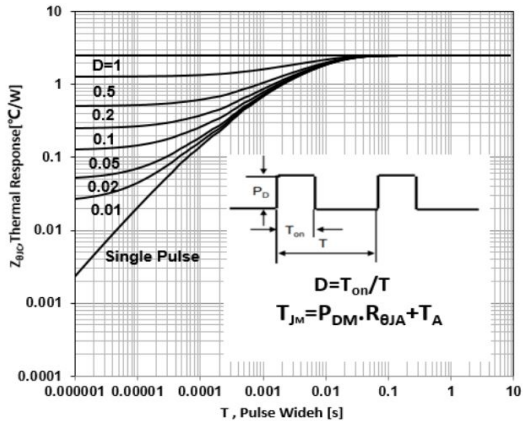


Fig 10. Inductive Switching Test Circuit

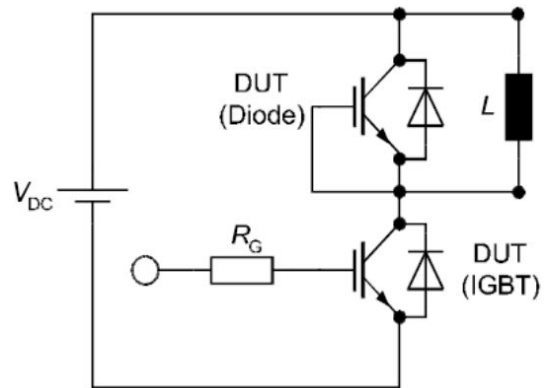


Fig 11. Inductive Switching Waveforms

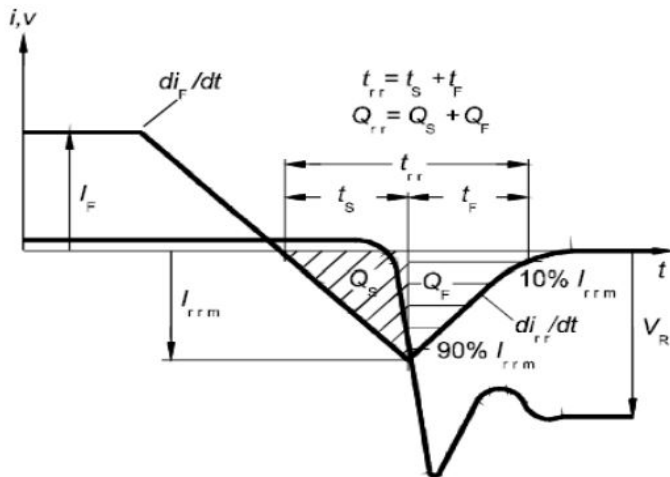




Fig 12. Inductive Switching Waveforms

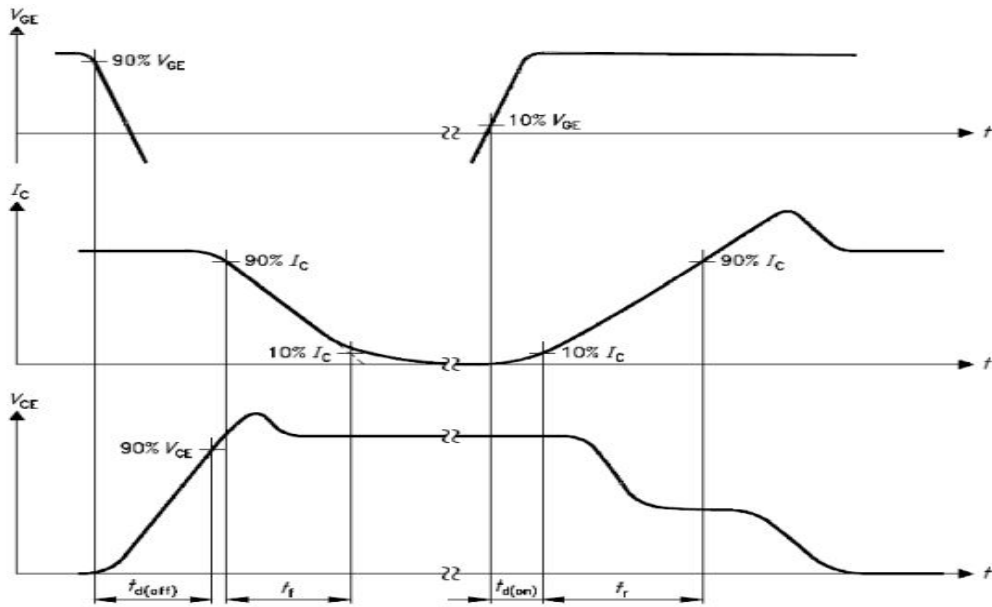
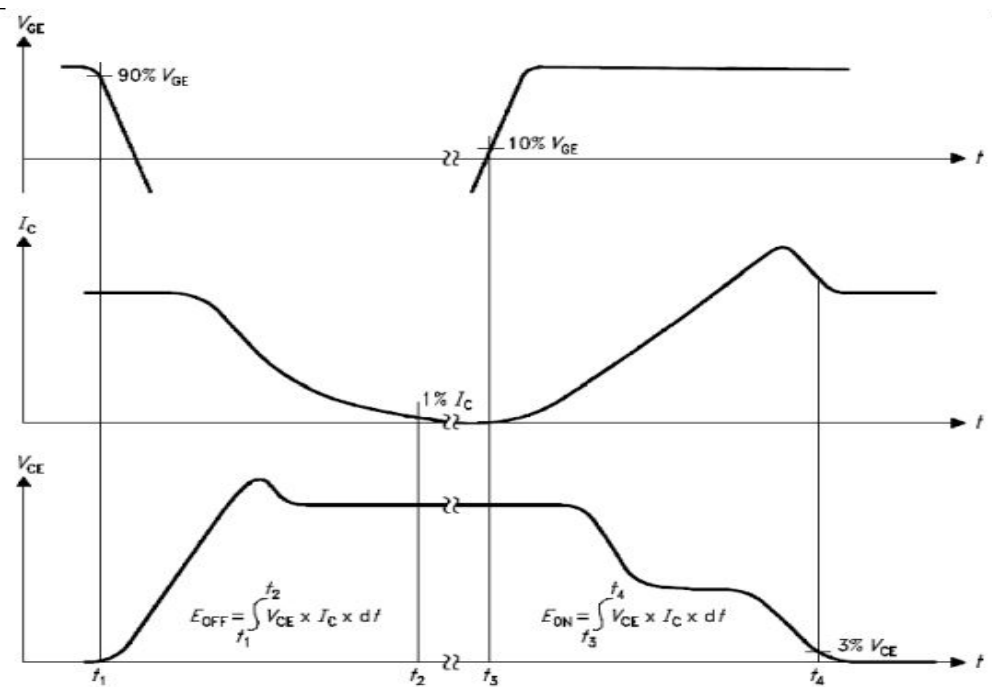


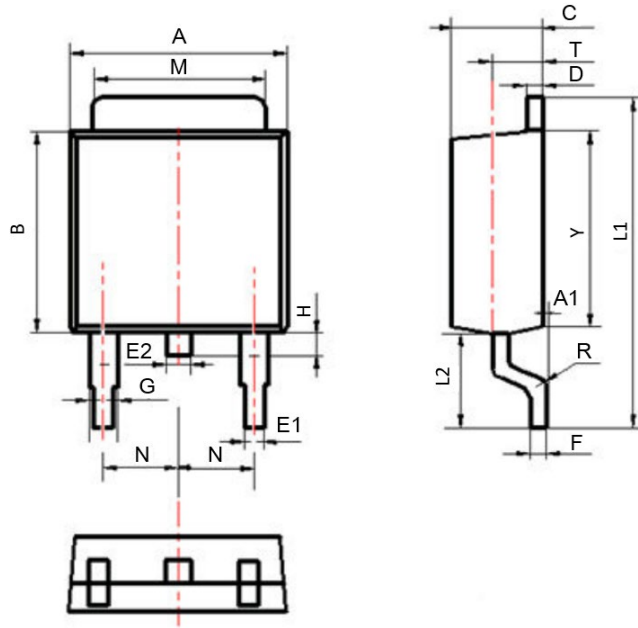
Fig 12. Inductive Switching Waveforms





**PACKAGE INFORMATION**

Dimension in TO-252 (Unit: mm)



Symbol	Min.	Max.
A	6.30	6.90
A1	0	0.13
B	5.70	6.30
C	2.10	2.50
D	0.30	0.60
E1	0.60	0.90
E2	0.70	1.00
F	0.30	0.60
G	0.70	1.20
L1	9.60	10.50
L2	2.70	3.10
H	0.60	1.00
M	5.10	5.50
N	2.09	2.49
R	0.3	
T	1.40	1.60
Y	5.10	6.30



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